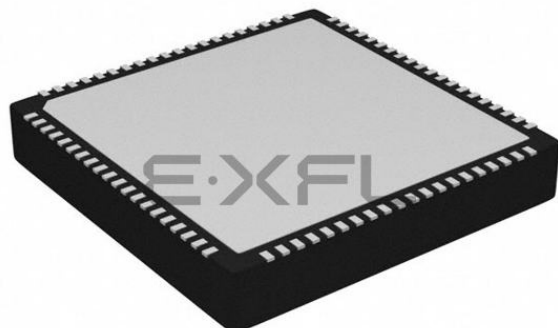




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Details

Product Status	Discontinued at Digi-Key
Core Processor	ARM® Cortex®-M0+
Core Size	32-Bit Single-Core
Speed	48MHz
Connectivity	CANbus, I ² C, IrDA, LINbus, SmartCard, SPI, UART/USART
Peripherals	Brown-out Detect/Reset, DMA, I ² S, LCD, POR, PWM, WDT
Number of I/O	67
Program Memory Size	128KB (128K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	1.8V ~ 3.8V
Data Converters	A/D 12bit SAR; D/A 12bit
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	80-WFQFN Exposed Pad
Supplier Device Package	80-QFN (9x9)
Purchase URL	https://www.e-xfl.com/product-detail/silicon-labs/efm32tg11b520f128gm80-ar

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3.6.5 Controller Area Network (CAN)

The CAN peripheral provides support for communication at up to 1 Mbps over CAN protocol version 2.0 part A and B. It includes 32 message objects with independent identifier masks and retains message RAM in EM2. Automatic retransmission may be disabled in order to support Time Triggered CAN applications.

3.6.6 Peripheral Reflex System (PRS)

The Peripheral Reflex System provides a communication network between different peripheral modules without software involvement. Peripheral modules producing Reflex signals are called producers. The PRS routes Reflex signals from producers to consumer peripherals which in turn perform actions in response. Edge triggers and other functionality such as simple logic operations (AND, OR, NOT) can be applied by the PRS to the signals. The PRS allows peripheral to act autonomously without waking the MCU core, saving power.

3.6.7 Low Energy Sensor Interface (LESENSE)

The Low Energy Sensor Interface LESENSE™ is a highly configurable sensor interface with support for up to 16 individually configurable sensors. By controlling the analog comparators, ADC, and DAC, LESENSE is capable of supporting a wide range of sensors and measurement schemes, and can for instance measure LC sensors, resistive sensors and capacitive sensors. LESENSE also includes a programmable finite state machine which enables simple processing of measurement results without CPU intervention. LESENSE is available in energy mode EM2, in addition to EM0 and EM1, making it ideal for sensor monitoring in applications with a strict energy budget.

3.7 Security Features

3.7.1 GPCRC (General Purpose Cyclic Redundancy Check)

The GPCRC module implements a Cyclic Redundancy Check (CRC) function. It supports both 32-bit and 16-bit polynomials. The supported 32-bit polynomial is 0x04C11DB7 (IEEE 802.3), while the 16-bit polynomial can be programmed to any value, depending on the needs of the application.

3.7.2 Crypto Accelerator (CRYPTO)

The Crypto Accelerator is a fast and energy-efficient autonomous hardware encryption and decryption accelerator. Tiny Gecko Series 1 devices support AES encryption and decryption with 128- or 256-bit keys, ECC over both GF(P) and GF(2^m), and SHA-1 and SHA-2 (SHA-224 and SHA-256).

Supported block cipher modes of operation for AES include: ECB, CTR, CBC, PCBC, CFB, OFB, GCM, CBC-MAC, GMAC and CCM.

Supported ECC NIST recommended curves include P-192, P-224, P-256, K-163, K-233, B-163 and B-233.

The CRYPTO module allows fast processing of GCM (AES), ECC and SHA with little CPU intervention. CRYPTO also provides trigger signals for DMA read and write operations.

3.7.3 True Random Number Generator (TRNG)

The TRNG module is a non-deterministic random number generator based on a full hardware solution. The TRNG is validated with NIST800-22 and AIS-31 test suites as well as being suitable for FIPS 140-2 certification (for the purposes of cryptographic key generation).

3.7.4 Security Management Unit (SMU)

The Security Management Unit (SMU) allows software to set up fine-grained security for peripheral access, which is not possible in the Memory Protection Unit (MPU). Peripherals may be secured by hardware on an individual basis, such that only privileged accesses to the peripheral's register interface will be allowed. When an access fault occurs, the SMU reports the specific peripheral involved and can optionally generate an interrupt.

3.8 Analog

4.1.6.3 Current Consumption 1.8 V without DC-DC Converter

Unless otherwise indicated, typical conditions are: VREGVDD = AVDD = DVDD = 1.8 V. T = 25 °C. DCDC is off. Minimum and maximum values in this table represent the worst conditions across supply voltage and process variation at T = 25 °C.

Table 4.8. Current Consumption 1.8 V without DC-DC Converter

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Current consumption in EM0 mode with all peripherals disabled	I _{ACTIVE}	48 MHz crystal, CPU running while loop from flash	—	45	—	μA/MHz
		48 MHz HFRCO, CPU running while loop from flash	—	44	—	μA/MHz
		48 MHz HFRCO, CPU running Prime from flash	—	57	—	μA/MHz
		48 MHz HFRCO, CPU running CoreMark loop from flash	—	71	—	μA/MHz
		32 MHz HFRCO, CPU running while loop from flash	—	45	—	μA/MHz
		26 MHz HFRCO, CPU running while loop from flash	—	46	—	μA/MHz
		16 MHz HFRCO, CPU running while loop from flash	—	49	—	μA/MHz
		1 MHz HFRCO, CPU running while loop from flash	—	158	—	μA/MHz
Current consumption in EM0 mode with all peripherals disabled and voltage scaling enabled	I _{ACTIVE_VS}	19 MHz HFRCO, CPU running while loop from flash	—	41	—	μA/MHz
		1 MHz HFRCO, CPU running while loop from flash	—	142	—	μA/MHz
Current consumption in EM1 mode with all peripherals disabled	I _{EM1}	48 MHz crystal	—	34	—	μA/MHz
		48 MHz HFRCO	—	33	—	μA/MHz
		32 MHz HFRCO	—	34	—	μA/MHz
		26 MHz HFRCO	—	35	—	μA/MHz
		16 MHz HFRCO	—	39	—	μA/MHz
		1 MHz HFRCO	—	147	—	μA/MHz
Current consumption in EM1 mode with all peripherals disabled and voltage scaling enabled	I _{EM1_VS}	19 MHz HFRCO	—	32	—	μA/MHz
		1 MHz HFRCO	—	133	—	μA/MHz
Current consumption in EM2 mode, with voltage scaling enabled	I _{EM2_VS}	Full 32 kB RAM retention and RTCC running from LFXO	—	1.39	—	μA
		Full 32 kB RAM retention and RTCC running from LFRCO	—	1.63	—	μA
		8 kB (1 bank) RAM retention and RTCC running from LFRCO ²	—	1.37	—	μA
Current consumption in EM3 mode, with voltage scaling enabled	I _{EM3_VS}	Full 32 kB RAM retention and CRYOTIMER running from ULFR-CO	—	1.10	—	μA

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Current consumption in EM4H mode, with voltage scaling enabled	I _{EM4H_VS}	128 byte RAM retention, RTCC running from LFXO	—	0.75	—	μA
		128 byte RAM retention, CRYO-TIMER running from ULFRCO	—	0.37	—	μA
		128 byte RAM retention, no RTCC	—	0.37	—	μA
Current consumption in EM4S mode	I _{EM4S}	No RAM retention, no RTCC	—	0.05	—	μA
Current consumption of peripheral power domain 1, with voltage scaling enabled	I _{PD1_VS}	Additional current consumption in EM2/3 when any peripherals on power domain 1 are enabled ¹	—	0.18	—	μA
Current consumption of peripheral power domain 2, with voltage scaling enabled	I _{PD2_VS}	Additional current consumption in EM2/3 when any peripherals on power domain 2 are enabled ¹	—	0.18	—	μA

Note:

1. Extra current consumed by power domain. Does not include current associated with the enabled peripherals. See [3.2.3 EM2 and EM3 Power Domains](#) for a list of the peripherals in each power domain.
2. CMU_LFRCOCTRL_ENVREF = 1, CMU_LFRCOCTRL_VREFUPDATE = 1

4.1.9.3 Low-Frequency RC Oscillator (LFRCO)

Table 4.13. Low-Frequency RC Oscillator (LFRCO)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Oscillation frequency	f _{LFRCO}	ENVREF ² = 1	TBD	32.768	TBD	kHz
		ENVREF ² = 1, T > 85 °C	TBD	32.768	TBD	kHz
		ENVREF ² = 0	TBD	32.768	TBD	kHz
Startup time	t _{LFRCO}		—	500	—	μs
Current consumption ¹	I _{LFRCO}	ENVREF = 1 in CMU_LFRCOCTRL	—	370	—	nA
		ENVREF = 0 in CMU_LFRCOCTRL	—	520	—	nA

Note:
1. Block is supplied by AVDD if ANASW = 0, or DVDD if ANASW=1 in EMU_PWRCTRL register.
2. In CMU_LFRCOCTRL register.

4.1.9.5 Auxiliary High-Frequency RC Oscillator (AUXHFRCO)

Table 4.15. Auxiliary High-Frequency RC Oscillator (AUXHFRCO)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Frequency accuracy	$f_{\text{AUXHFRCO_ACC}}$	At production calibrated frequencies, across supply voltage and temperature	TBD	—	TBD	%
Start-up time	t_{AUXHFRCO}	$f_{\text{AUXHFRCO}} \geq 19 \text{ MHz}$	—	400	—	ns
		$4 < f_{\text{AUXHFRCO}} < 19 \text{ MHz}$	—	1.4	—	μs
		$f_{\text{AUXHFRCO}} \leq 4 \text{ MHz}$	—	2.5	—	μs
Current consumption on all supplies	I_{AUXHFRCO}	$f_{\text{AUXHFRCO}} = 48 \text{ MHz}$	—	238	TBD	μA
		$f_{\text{AUXHFRCO}} = 38 \text{ MHz}$	—	196	TBD	μA
		$f_{\text{AUXHFRCO}} = 32 \text{ MHz}$	—	160	TBD	μA
		$f_{\text{AUXHFRCO}} = 26 \text{ MHz}$	—	137	TBD	μA
		$f_{\text{AUXHFRCO}} = 19 \text{ MHz}$	—	110	TBD	μA
		$f_{\text{AUXHFRCO}} = 16 \text{ MHz}$	—	101	TBD	μA
		$f_{\text{AUXHFRCO}} = 13 \text{ MHz}$	—	78	TBD	μA
		$f_{\text{AUXHFRCO}} = 7 \text{ MHz}$	—	54	TBD	μA
		$f_{\text{AUXHFRCO}} = 4 \text{ MHz}$	—	30	TBD	μA
		$f_{\text{AUXHFRCO}} = 2 \text{ MHz}$	—	27	TBD	μA
		$f_{\text{AUXHFRCO}} = 1 \text{ MHz}$	—	25	TBD	μA
Coarse trim step size (% of period)	$SS_{\text{AUXHFRCO_COARSE}}$		—	0.8	—	%
Fine trim step size (% of period)	$SS_{\text{AUXHFRCO_FINE}}$		—	0.1	—	%
Period jitter	PJ_{AUXHFRCO}		—	0.2	—	% RMS

4.1.9.6 Ultra-low Frequency RC Oscillator (ULFRCO)

Table 4.16. Ultra-low Frequency RC Oscillator (ULFRCO)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Oscillation frequency	f_{ULFRCO}		TBD	1	TBD	kHz

4.1.14 Analog Comparator (ACMP)

Table 4.21. Analog Comparator (ACMP)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Input voltage range	V_{ACMPIN}	ACMPVDD = ACMPn_CTRL_PWRSEL ¹	—	—	$V_{ACMPVDD}$	V
Supply voltage	$V_{ACMPVDD}$	BIASPROG ⁴ ≤ 0x10 or FULL- BIAS ⁴ = 0	1.8	—	$V_{VREGVDD_MAX}$	V
		0x10 < BIASPROG ⁴ ≤ 0x20 and FULLBIAS ⁴ = 1	2.1	—	$V_{VREGVDD_MAX}$	V
Active current not including voltage reference ²	I_{ACMP}	BIASPROG ⁴ = 1, FULLBIAS ⁴ = 0	—	50	—	nA
		BIASPROG ⁴ = 0x10, FULLBIAS ⁴ = 0	—	306	—	nA
		BIASPROG ⁴ = 0x02, FULLBIAS ⁴ = 1	—	6.5	—	μA
		BIASPROG ⁴ = 0x20, FULLBIAS ⁴ = 1	—	74	TBD	μA
Current consumption of inter- nal voltage reference ²	$I_{ACMPREF}$	VLP selected as input using 2.5 V Reference / 4 (0.625 V)	—	50	—	nA
		VLP selected as input using VDD	—	20	—	nA
		VBDIV selected as input using 1.25 V reference / 1	—	4.1	—	μA
		VADIV selected as input using VDD/1	—	2.4	—	μA

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Open-loop gain	G _{OL}	DRIVESTRENGTH = 3	—	135	—	dB
		DRIVESTRENGTH = 2	—	137	—	dB
		DRIVESTRENGTH = 1	—	121	—	dB
		DRIVESTRENGTH = 0	—	109	—	dB
Loop unit-gain frequency ⁷	UGF	DRIVESTRENGTH = 3, Buffer connection	—	3.38	—	MHz
		DRIVESTRENGTH = 2, Buffer connection	—	0.9	—	MHz
		DRIVESTRENGTH = 1, Buffer connection	—	132	—	kHz
		DRIVESTRENGTH = 0, Buffer connection	—	34	—	kHz
		DRIVESTRENGTH = 3, 3x Gain connection	—	2.57	—	MHz
		DRIVESTRENGTH = 2, 3x Gain connection	—	0.71	—	MHz
		DRIVESTRENGTH = 1, 3x Gain connection	—	113	—	kHz
		DRIVESTRENGTH = 0, 3x Gain connection	—	28	—	kHz
Phase margin	PM	DRIVESTRENGTH = 3, Buffer connection	—	67	—	°
		DRIVESTRENGTH = 2, Buffer connection	—	69	—	°
		DRIVESTRENGTH = 1, Buffer connection	—	63	—	°
		DRIVESTRENGTH = 0, Buffer connection	—	68	—	°
Output voltage noise	N _{OUT}	DRIVESTRENGTH = 3, Buffer connection, 10 Hz - 10 MHz	—	146	—	μVrms
		DRIVESTRENGTH = 2, Buffer connection, 10 Hz - 10 MHz	—	163	—	μVrms
		DRIVESTRENGTH = 1, Buffer connection, 10 Hz - 1 MHz	—	170	—	μVrms
		DRIVESTRENGTH = 0, Buffer connection, 10 Hz - 1 MHz	—	176	—	μVrms
		DRIVESTRENGTH = 3, 3x Gain connection, 10 Hz - 10 MHz	—	313	—	μVrms
		DRIVESTRENGTH = 2, 3x Gain connection, 10 Hz - 10 MHz	—	271	—	μVrms
		DRIVESTRENGTH = 1, 3x Gain connection, 10 Hz - 1 MHz	—	247	—	μVrms
		DRIVESTRENGTH = 0, 3x Gain connection, 10 Hz - 1 MHz	—	245	—	μVrms

4.1.21.2 I2C Fast-mode (Fm)¹

Table 4.29. I2C Fast-mode (Fm)¹

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
SCL clock frequency ²	f _{SCL}		0	—	400	kHz
SCL clock low time	t _{LOW}		1.3	—	—	μs
SCL clock high time	t _{HIGH}		0.6	—	—	μs
SDA set-up time	t _{SU_DAT}		100	—	—	ns
SDA hold time ³	t _{HD_DAT}		100	—	900	ns
Repeated START condition set-up time	t _{SU_STA}		0.6	—	—	μs
(Repeated) START condition hold time	t _{HD_STA}		0.6	—	—	μs
STOP condition set-up time	t _{SU_STO}		0.6	—	—	μs
Bus free time between a STOP and START condition	t _{BUF}		1.3	—	—	μs

Note:

1. For CLHR set to 1 in the I2Cn_CTRL register.
2. For the minimum HPERCLK frequency required in Fast-mode, refer to the I2C chapter in the reference manual.
3. The maximum SDA hold time (t_{HD,DAT}) needs to be met only when the device does not stretch the low time of SCL (t_{LOW}).

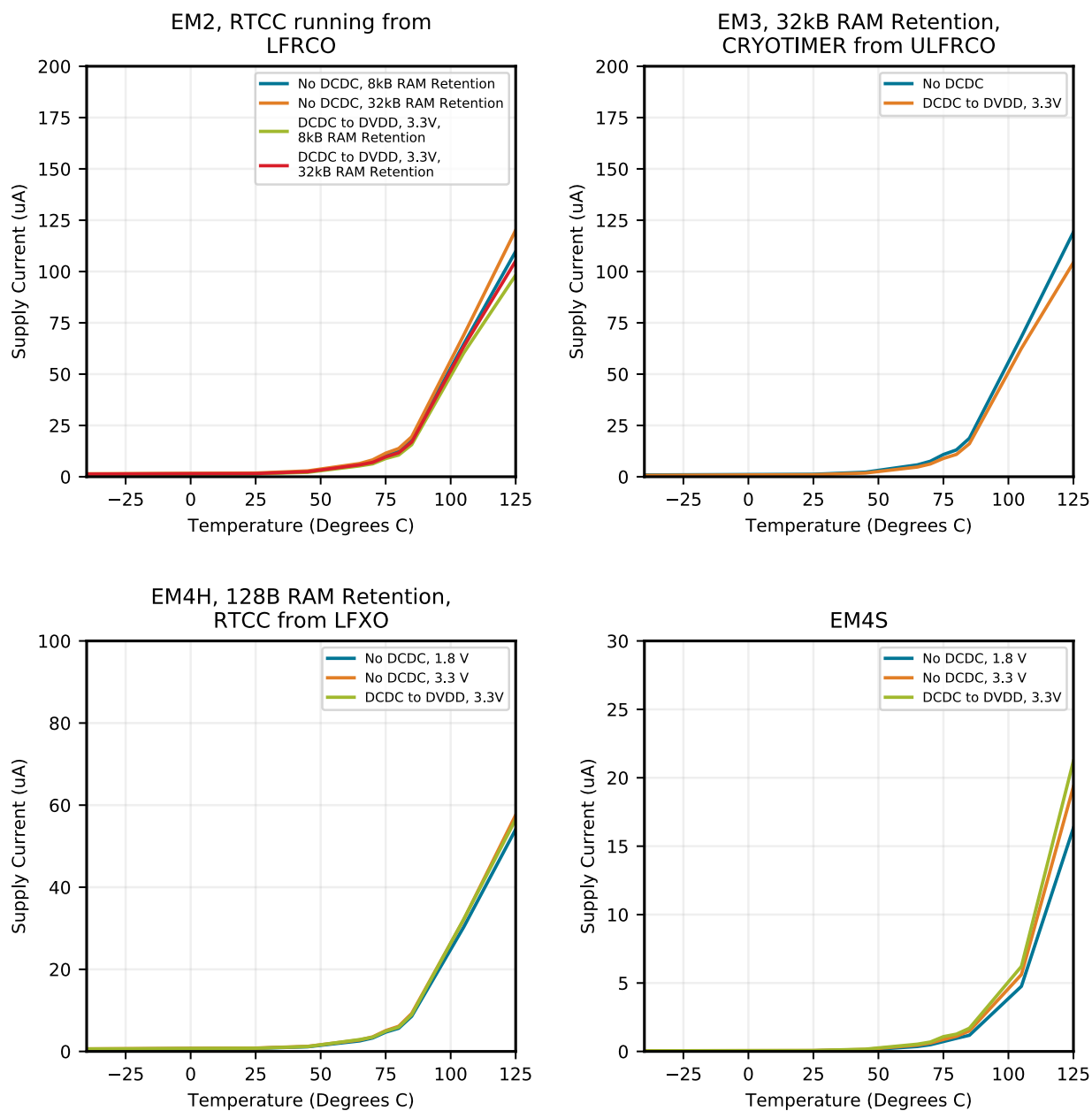


Figure 4.5. EM2, EM3, EM4H and EM4S Typical Supply Current vs. Temperature

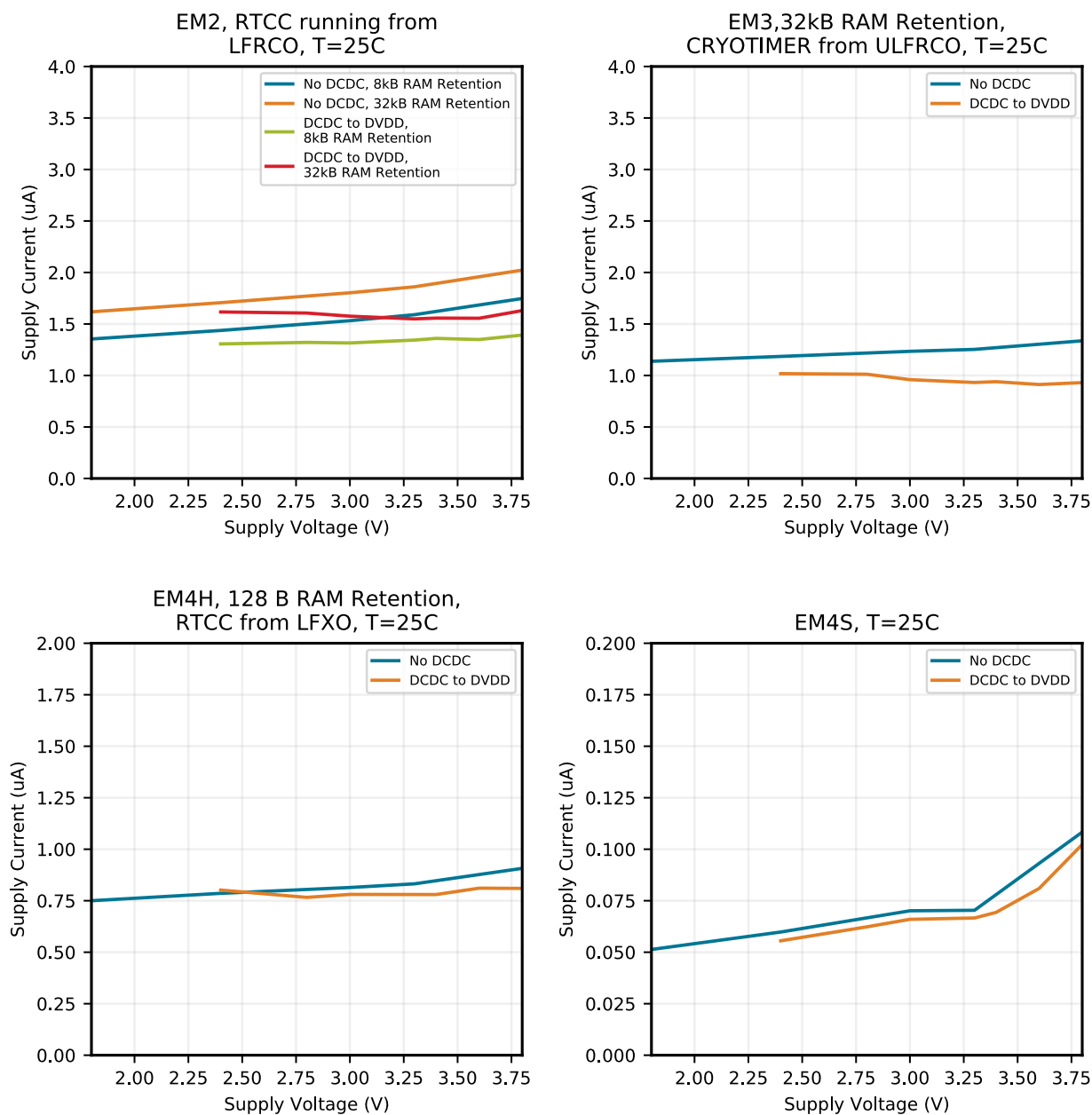


Figure 4.7. EM2, EM3, EM4H and EM4S Typical Supply Current vs. Supply

5.4 EFM32TG11B3xx in QFP64 Device Pinout

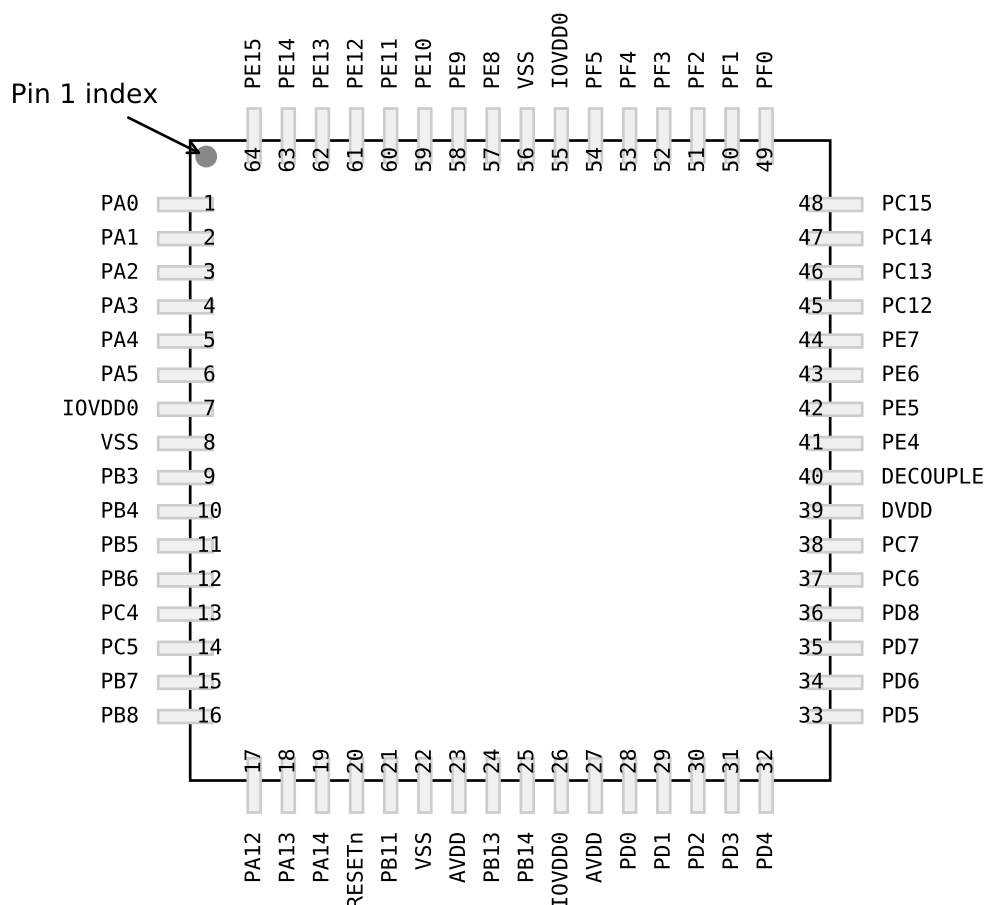


Figure 5.4. EFM32TG11B3xx in QFP64 Device Pinout

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see [5.14 GPIO Functionality Table](#) or [5.15 Alternate Functionality Overview](#).

Table 5.4. EFM32TG11B3xx in QFP64 Device Pinout

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
PA0	1	GPIO	PA1	2	GPIO
PA2	3	GPIO	PA3	4	GPIO
PA4	5	GPIO	PA5	6	GPIO
IOVDD0	7 26 55	Digital IO power supply 0.	VSS	8 22 56	Ground
PB3	9	GPIO	PB4	10	GPIO
PB5	11	GPIO	PB6	12	GPIO

5.6 EFM32TG11B5xx in QFN64 Device Pinout

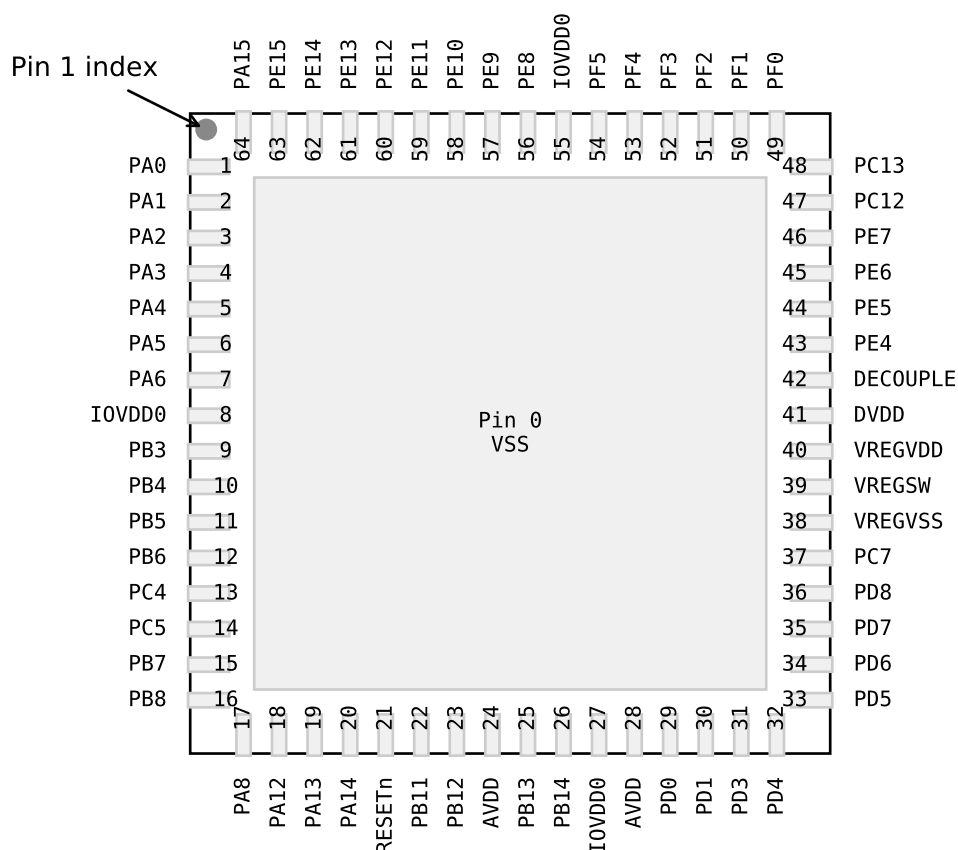


Figure 5.6. EFM32TG11B5xx in QFN64 Device Pinout

The following table provides package pin connections and general descriptions of pin functionality. For detailed information on the supported features for each GPIO pin, see [5.14 GPIO Functionality Table](#) or [5.15 Alternate Functionality Overview](#).

Table 5.6. EFM32TG11B5xx in QFN64 Device Pinout

Pin Name	Pin(s)	Description	Pin Name	Pin(s)	Description
VREGVSS	0 38	Voltage regulator VSS	PA0	1	GPIO
PA1	2	GPIO	PA2	3	GPIO
PA3	4	GPIO	PA4	5	GPIO
PA5	6	GPIO	PA6	7	GPIO
IOVDD0	8 27 55	Digital IO power supply 0.	PB3	9	GPIO

5.14 GPIO Functionality Table

A wide selection of alternate functionality is available for multiplexing to various pins. The following table shows the name of each GPIO pin, followed by the functionality available on that pin. Refer to [5.15 Alternate Functionality Overview](#) for a list of GPIO locations available for each function.

Table 5.14. GPIO Functionality Table

GPIO Name	Pin Alternate Functionality / Description			
	Analog	Timers	Communication	Other
PA0	BUSBY BUSAX LCD_SEG13	TIM0_CC0 #0 TIM0_CC1 #7 PCNT0_S0IN #4	US1_RX #5 US3_TX #0 LEU0_RX #4 I2C0_SDA #0	CMU_CLK2 #0 PRS_CH0 #0 PRS_CH3 #3 GPIO_EM4WU0
PA1	BUSAY BUSBX LCD_SEG14	TIM0_CC0 #7 TIM0_CC1 #0 PCNT0_S1IN #4	US3_RX #0 I2C0_SCL #0	CMU_CLK1 #0 PRS_CH1 #0
PA2	BUSBY BUSAX LCD_SEG15	TIM0_CC2 #0	US1_RX #6 US3_CLK #0	CMU_CLK0 #0
PA3	BUSAY BUSBX LCD_SEG16	TIM0_CDTI0 #0	US3_CS #0 U0_TX #2	CMU_CLK2 #1 CMU_CLK2 #4 CMU_CLKI0 #1 LES_AL- TEX2
PA4	BUSBY BUSAX LCD_SEG17	TIM0_CDTI1 #0	US3_CTS #0 U0_RX #2	LES_ALTEX3
PA5	BUSAY BUSBX LCD_SEG18	TIM0_CDTI2 #0	US3_RTS #0 U0_CTS #2	LES_ALTEX4 ACMP1_O #7
PA6	BUSBY BUSAX LCD_SEG19	WTIM0_CC0 #1	U0_RTS #2	PRS_CH6 #0 ACMP0_O #4 GPIO_EM4WU1
PB3	BUSAY BUSBX LCD_SEG20 / LCD_COM4	TIM1_CC3 #2 WTIM0_CC0 #6	US2_TX #1 US3_TX #2	ACMP0_O #7
PB4	BUSBY BUSAX LCD_SEG21 / LCD_COM5	WTIM0_CC1 #6	US2_RX #1	
PB5	BUSAY BUSBX LCD_SEG22 / LCD_COM6	WTIM0_CC2 #6 PCNT0_S0IN #6	US0_RTS #4 US2_CLK #1	
PB6	BUSBY BUSAX LCD_SEG23 / LCD_COM7	TIM0_CC0 #3 PCNT0_S1IN #6	US0_CTS #4 US2_CS #1	
PC0	VDAC0_OUT0ALT / OPA0_OUTALT #0 BU- SACMP0Y BUSACMP0X	TIM0_CC1 #3 PCNT0_S0IN #2	CAN0_RX #0 US0_TX #5 US1_TX #0 US1_CS #4 US2_RTS #0 US3_CS #3 I2C0_SDA #4	LES_CH0 PRS_CH2 #0
PC1	VDAC0_OUT0ALT / OPA0_OUTALT #1 BU- SACMP0Y BUSACMP0X	TIM0_CC2 #3 WTIM0_CC0 #7 PCNT0_S1IN #2	CAN0_TX #0 US0_RX #5 US1_TX #4 US1_RX #0 US2_CTS #0 US3_RTS #1 I2C0_SCL #4	LES_CH1 PRS_CH3 #0
PC2	VDAC0_OUT0ALT / OPA0_OUTALT #2 BU- SACMP0Y BUSACMP0X	TIM0_CDTI0 #3 WTIM0_CC1 #7	US1_RX #4 US2_TX #0	LES_CH2
PC3	VDAC0_OUT0ALT / OPA0_OUTALT #3 BU- SACMP0Y BUSACMP0X	TIM0_CDTI1 #3 WTIM0_CC2 #7	US1_CLK #4 US2_RX #0	LES_CH3

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
U0_TX	2: PA3 3: PC14	4: PC4 5: PF1 6: PD7	UART0 Transmit output. Also used as receive input in half duplex communication.
US0_CLK	0: PE12 1: PE5 2: PC9 3: PC15	4: PB13 5: PA12	USART0 clock input / output.
US0_CS	0: PE13 1: PE4 2: PC8 3: PC14	4: PB14 5: PA13	USART0 chip select input / output.
US0_CTS	0: PE14 2: PC7 3: PC13	4: PB6 5: PB11	USART0 Clear To Send hardware flow control input.
US0_RTS	0: PE15 2: PC6 3: PC12	4: PB5 5: PD6	USART0 Request To Send hardware flow control output.
US0_RX	0: PE11 1: PE6 2: PC10 3: PE12	4: PB8 5: PC1	USART0 Asynchronous Receive. USART0 Synchronous mode Master Input / Slave Output (MISO).
US0_TX	0: PE10 1: PE7 2: PC11 3: PE13	4: PB7 5: PC0	USART0 Asynchronous Transmit. Also used as receive input in half duplex communication. USART0 Synchronous mode Master Output / Slave Input (MOSI).
US1_CLK	0: PB7 1: PD2 2: PF0 3: PC15	4: PC3 5: PB11 6: PE5	USART1 clock input / output.
US1_CS	0: PB8 1: PD3 2: PF1 3: PC14	4: PC0 5: PE4	USART1 chip select input / output.
US1_CTS	1: PD4 2: PF3 3: PC6	4: PC12 5: PB13	USART1 Clear To Send hardware flow control input.
US1_RTS	1: PD5 2: PF4 3: PC7	4: PC13 5: PB14	USART1 Request To Send hardware flow control output.
US1_RX	0: PC1 1: PD1 2: PD6	4: PC2 5: PA0 6: PA2	USART1 Asynchronous Receive. USART1 Synchronous mode Master Input / Slave Output (MISO).
US1_TX	0: PC0 1: PD0 2: PD7	4: PC1 5: PF2 6: PA14	USART1 Asynchronous Transmit. Also used as receive input in half duplex communication. USART1 Synchronous mode Master Output / Slave Input (MOSI).

Alternate	LOCATION		
Functionality	0 - 3	4 - 7	Description
US2_CLK	0: PC4 1: PB5 2: PA9 3: PA15	5: PF2	USART2 clock input / output.
US2_CS	0: PC5 1: PB6 2: PA10 3: PB11	5: PF5	USART2 chip select input / output.
US2_CTS	0: PC1 1: PB12	4: PC12 5: PD6	USART2 Clear To Send hardware flow control input.
US2_RTS	0: PC0 2: PA12 3: PC14	4: PC13 5: PD8	USART2 Request To Send hardware flow control output.
US2_RX	0: PC3 1: PB4 2: PA8 3: PA14	5: PF1	USART2 Asynchronous Receive. USART2 Synchronous mode Master Input / Slave Output (MISO).
US2_TX	0: PC2 1: PB3 3: PA13	5: PF0	USART2 Asynchronous Transmit. Also used as receive input in half duplex communication. USART2 Synchronous mode Master Output / Slave Input (MOSI).
US3_CLK	0: PA2 1: PD7 2: PD4		USART3 clock input / output.
US3_CS	0: PA3 1: PE4 2: PC14 3: PC0		USART3 chip select input / output.
US3_CTS	0: PA4 1: PE5 2: PD6		USART3 Clear To Send hardware flow control input.
US3_RTS	0: PA5 1: PC1 2: PA14 3: PC15		USART3 Request To Send hardware flow control output.
US3_RX	0: PA1 1: PE7 2: PB7		USART3 Asynchronous Receive. USART3 Synchronous mode Master Input / Slave Output (MISO).
US3_TX	0: PA0 1: PE6 2: PB3		USART3 Asynchronous Transmit. Also used as receive input in half duplex communication. USART3 Synchronous mode Master Output / Slave Input (MOSI).
VDAC0_EXT	0: PD6		Digital to analog converter VDAC0 external reference input pin.

Table 5.19. CSEN Bus and Pin Mapping

[illegible]

Table 6.1. TQFP80 Package Dimensions

Dimension	Min	Typ	Max
A	—	—	1.20
A1	0.05	—	0.15
A2	0.95	1.00	1.05
b	0.17	0.20	0.27
c	0.09	—	0.20
D	14.00 BSC		
D1	12.00 BSC		
e	0.50 BSC		
E	14.00 BSC		
E1	12.00 BSC		
L	0.45	0.60	0.75
L1	1.00 REF		
θ	0	3.5	7
aaa	0.20		
bbb	0.20		
ccc	0.08		
ddd	0.08		
eee	0.05		

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.
3. This package outline conforms to JEDEC MS-026, variant ADD.
4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020C specification for Small Body Components.

Table 7.2. QFN80 PCB Land Pattern Dimensions

Dimension	Typ
C1	8.90
C2	8.90
E	0.40
X1	0.20
Y1	0.85
X2	7.30
Y2	7.30

Note:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.
2. This Land Pattern Design is based on the IPC-7351 guidelines.
3. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05mm.
4. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 μ m minimum, all the way around the pad.
5. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
6. The stencil thickness should be 0.125 mm (5 mils).
7. The ratio of stencil aperture to land pad size can be 1:1 for all pads.
8. A 3x3 array of 1.45 mm square openings on a 2.00 mm pitch can be used for the center ground pad.
9. A No-Clean, Type-3 solder paste is recommended.
10. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.